

TLP250F(INV)

Transistor Inverters
Inverter for Air Conditioners
IGBT Gate Drivers
Power MOSFET Gate Drivers

The TOSHIBA TLP250F(INV) consists of a GaAlAs light emitting diode optically coupled to an integrated photodetector and is housed in an 8-pin DIP package.
The TLP250F(INV) is suitable for gate driving circuitry of IGBTs or power MOSFETs.
Absolute maximum ratings and electrical characteristics are the same as those of the TLP250(INV) and listed in its datasheet.

- Input threshold current: $I_F = 5\text{ mA (max)}$
- Supply current : 11 mA (max)
- Supply voltage : $10\text{ V to }35\text{ V}$
- Output current : $\pm 1.5\text{ A (max)}$
- Switching time : $t_{pHL}, t_{pLH} = 0.5\text{ }\mu\text{s (max)}$
- Isolation voltage : $2500\text{ V}_{rms}\text{ (min)}$
- UL recognized : UL1577, file no. E67349
- Option (D4) type
VDE approved: DIN EN 60747-5-2, certificate No. 40011913
Maximum operating insulation voltage: 1140 VPK
Maximum permissible overvoltage: 6000 VPK

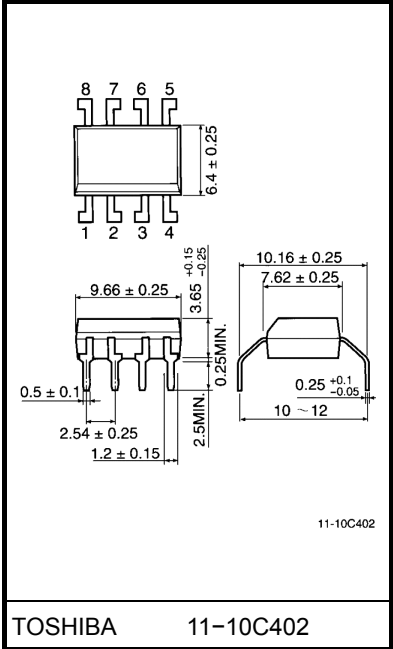
(Note 1) When an EN 60747-5-2 approved type is needed, please designate the “ Option (D4) ”.

- Structural parameter
Creepage distance: 8.0 mm (min)
Clearance: 8.0 mm (min)

Truth Table

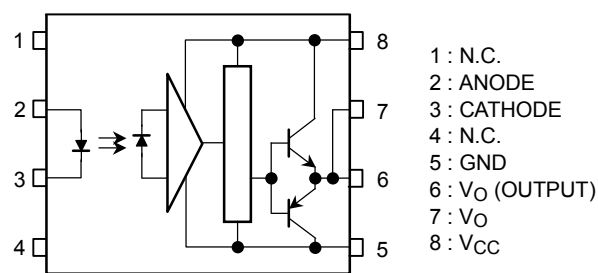
		Tr1	Tr2
Input LED	On	On	Off
	Off	Off	On

Unit: mm

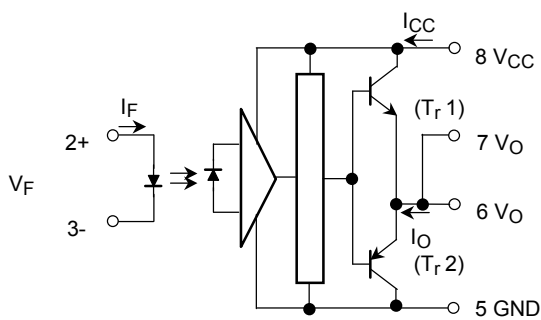


Weight: 0.54 g

Pin Configuration (top view)



Schematic



(Note 2) A 0.1 μ F bypass capacitor must be connected between pin 8 and 5.

RESTRICTIONS ON PRODUCT USE

20070701-EN GENERAL

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- The products described in this document shall not be used or embedded to any downstream products of which manufacture, use and/or sale are prohibited under any applicable laws and regulations.
- GaAs(Gallium Arsenide) is used in this product. The dust or vapor is harmful to the human body. Do not break, cut, crush or dissolve chemically.
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